



UTG40N120LLS1

Insulated Gate Bipolar Transistor

1200V TRENCH GATE FIELD-STOP IGBT

■ DESCRIPTION

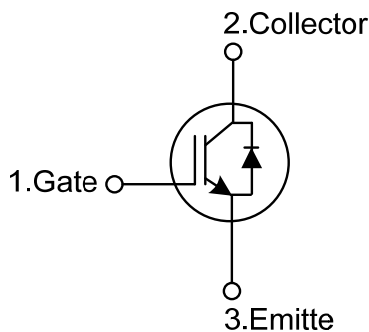
The UTC **UTG40N120LLS1** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

The UTC **UTG40N120LLS1** is suitable for the resonant or soft switching applications.

■ FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: $V_{CE(SAT).Typ.} = 1.5V @ I_C=40A, V_{GE}=15V$ ($T_C = 25^{\circ}C$)

■ SYMBOL

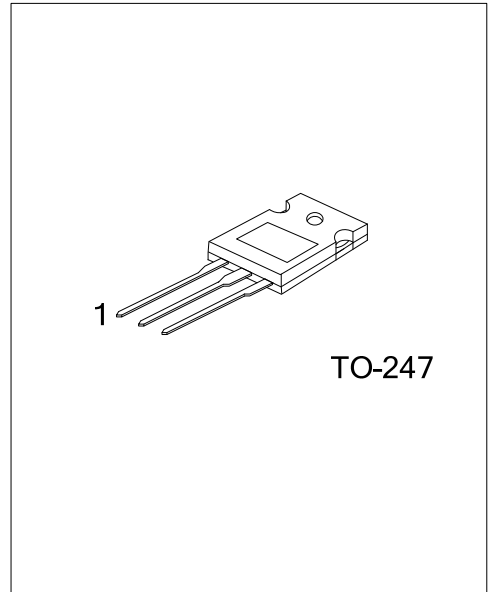


■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UTG40N120LLS1L-T47-T	UTG40N120LLS1G-T47-T	TO-247	G	C	E	Tube

Note: Pin Assignment: G: Gate C: Collector E: Emitter

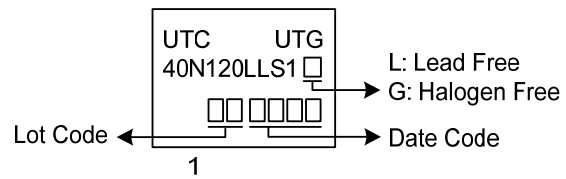
UTG40N120LLS1G-T47-T		(1) Packing Type	(1) T: Tube
		(2) Package Type	(2) T47: TO-247
		(3) Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free



UTG40N120LLS1

Insulated Gate Bipolar Transistor

■ MARKING



■ **ABSOLUTE MAXIMUM RATINGS** ($T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage	V_{CES}	1200	V
Gate-Emitter Voltage	V_{GES}	± 20	V
Transient Gate-emitter voltage ($t_p < 5 \text{ ms}$)		± 25	V
Continuous Collector Current	I_C	$T_C=25^{\circ}\text{C}$	A
		$T_C=100^{\circ}\text{C}$	A
Collector Current Pulsed (Note 1)	I_{CM}	160	A
Diode Forward Current	I_F	$T_C=25^{\circ}\text{C}$	A
		$T_C=100^{\circ}\text{C}$	A
Short Circuit Withstand Time $V_{GE} = 15\text{V}$, $V_{CC} \leq 200\text{V}$ Allowed number of short circuits < 1000 Time between short circuits: $\geq 1.0\text{s}$ $T_{VJ} = 25^{\circ}\text{C}$	t_{SC}	8	μs
Power Dissipation ($T_C=25^{\circ}\text{C}$)	P_D	285	W
Operating Junction Temperature	T_J	$-40 \sim +150$	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	$-55 \sim +150$	$^{\circ}\text{C}$

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Absolute maximum ratings are those values beyond which the device could be permanently damaged.

2. Pulse width limited by maximum junction temperature.

■ **THERMAL DATA**

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θ_{JC}	0.44	$^{\circ}\text{C/W}$

■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Off Characteristics						
Collector-Emitter Breakdown Voltage	BV _{CES}		1200			V
Collector Cut-Off Current	I _{CES}	V _{CE} =1200V, V _{GE} =0V			5	μA
G-E Leakage Current	I _{GES}	V _{CE} =0V, V _{GE} =±20V			±400	nA
On Characteristics						
Gate to Emitter Threshold Voltage	V _{GE(TH)}	I _C =250μA, V _{CE} =V _{GE}	4.5		7.5	V
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =40A, V _{GE} =15V	T _C =25°C	1.5	2.0	V
			T _C =125°C	1.7		V
Dynamic Characteristics						
Input Capacitance	C _{IES}	V _{CE} =25V, V _{GE} =0V, f=1MHz		2550		pF
Output Capacitance	C _{OES}			221		pF
Reverse Transfer Capacitance	C _{RES}			64		pF
Switching Characteristics						
Total Gate Charge	Q _G	V _{CE} =600V, I _C =40A, V _{GE} =15V		132		nC
Gate-Emitter Charge	Q _{GE}			29		nC
Gate-Collector Charge	Q _{GC}			68		nC
Turn-On Delay Time	t _{DON}	V _{CC} =600V, I _C =40A, R _G =5Ω, V _{GE} =0~15V, L=500μH		16		ns
Rise Time	t _R			35		ns
Turn-Off Delay Time	t _{DOFF}			171		ns
Fall Time	t _F			160		ns
Turn-On Switching Loss	E _{ON}			3		mJ
Turn-Off Switching Loss	E _{OFF}			3		mJ
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Forward Voltage Drop	V _F	I _F =40A			2.5	V
Reverse Recovery Time	t _{rr}	I _F =40A, dI/dt=100A/μS,		70		ns
Reverse Recovery Charge	Q _{rr}	V _{CC} =400V		1408		nC

■ TEST CIRCUIT AND WAVEFORMS

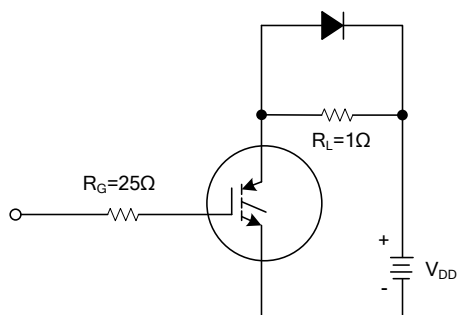


Fig 1. INDUCTIVE SWITCHING TEST CIRCUIT

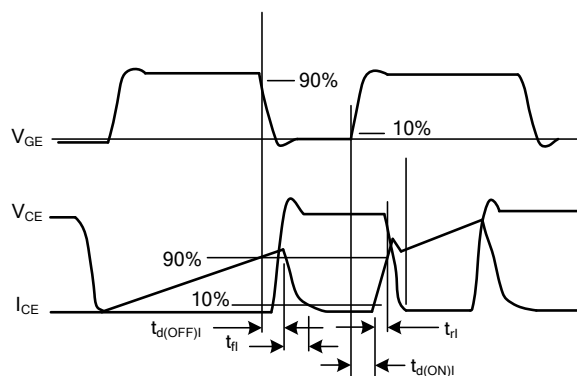
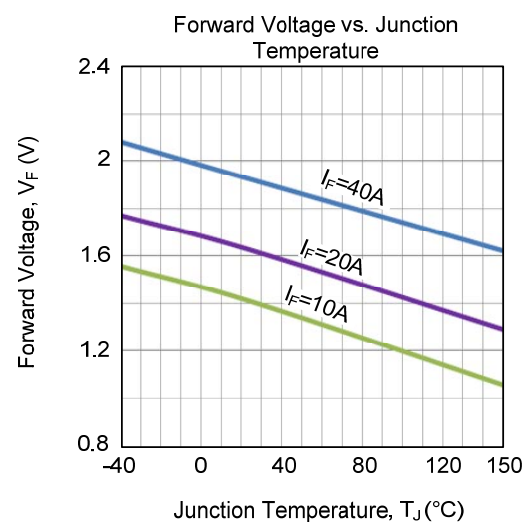
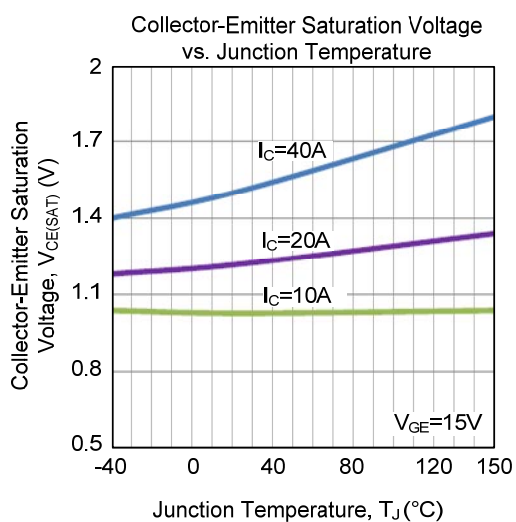
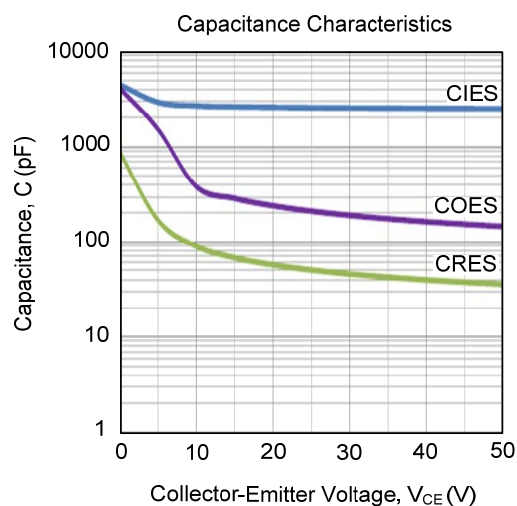
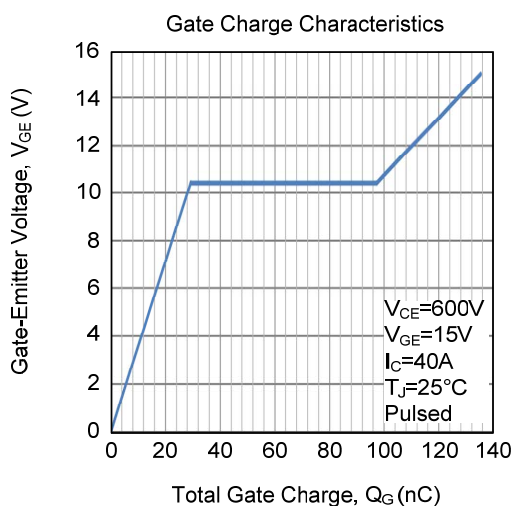
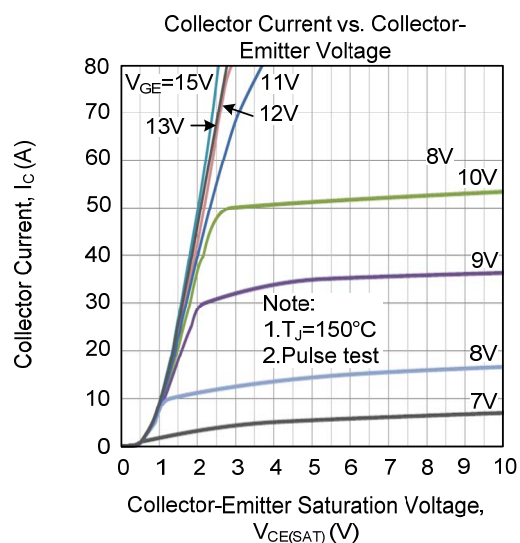
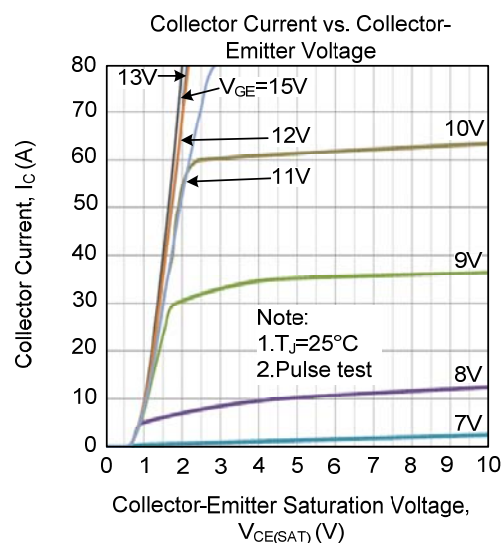
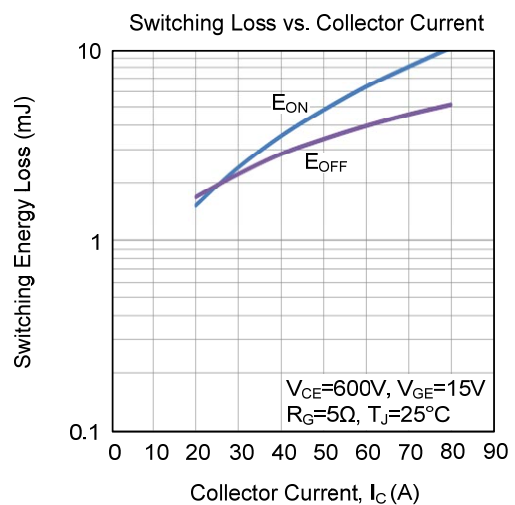
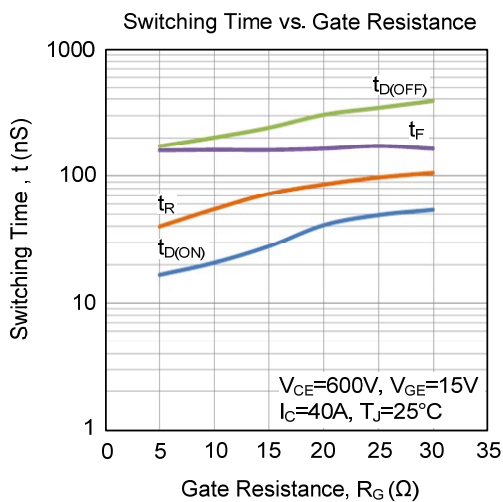
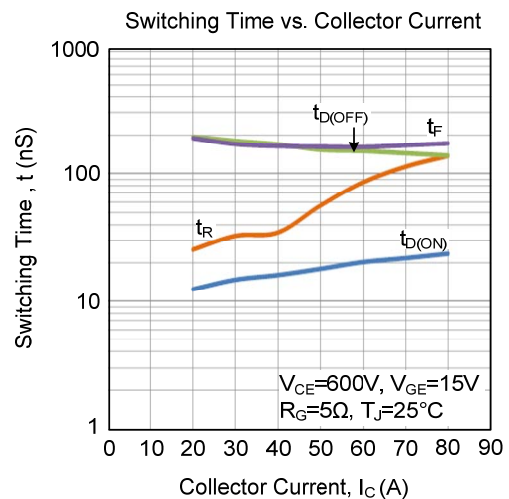
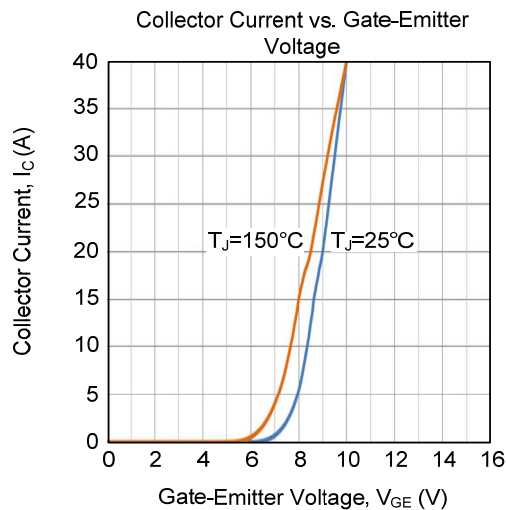
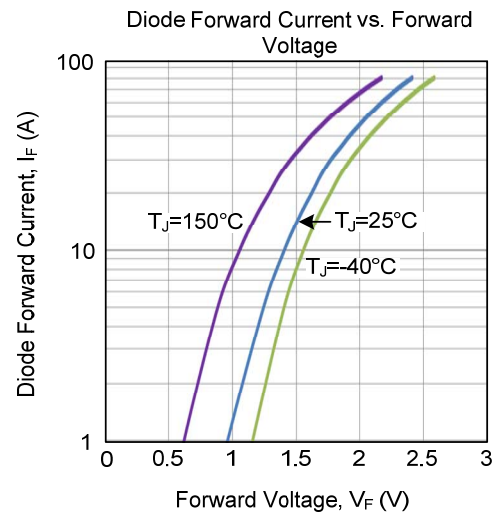
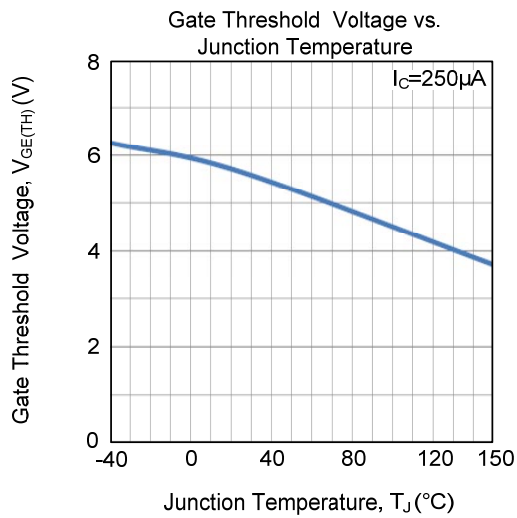


Fig 2. SWITCHING TEST WAVEFORMS

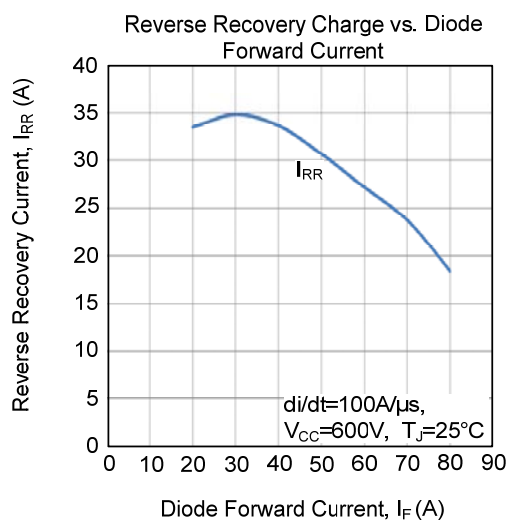
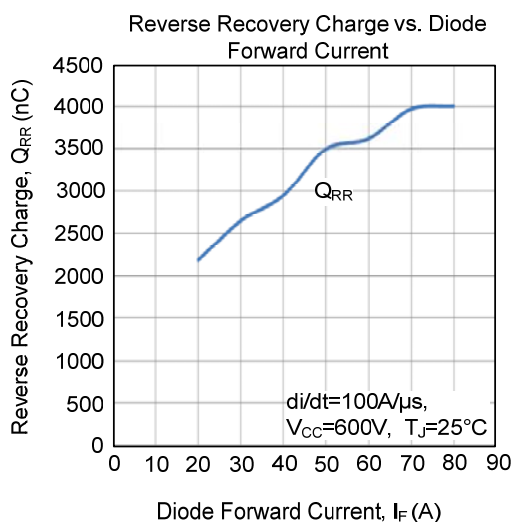
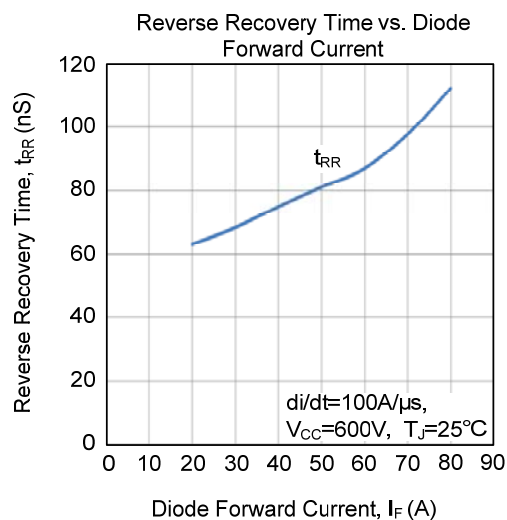
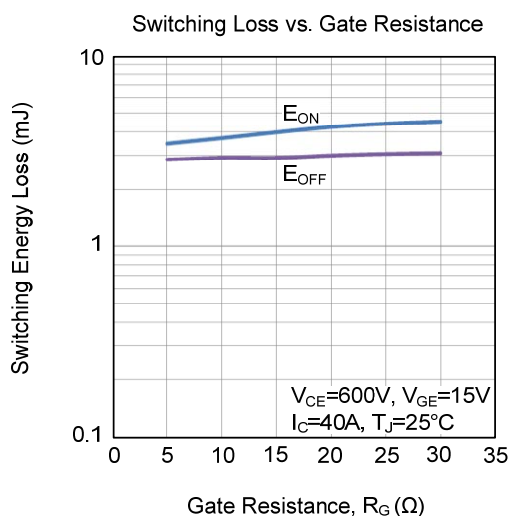
■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



■ TYPICAL CHARACTERISTICS (Cont.)



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